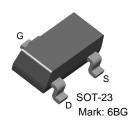


MMBF4416A N-Channel RF Amplifier

- This device is designed for RF amplifiers.
- Sourced from process 50.



$\begin{tabular}{lll} \textbf{Absolute Maximum Ratings*} & $T_a = 25^{\circ}C$ unless otherwise noted \\ \end{tabular}$

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	35	V
V_{GS}	Gate-Source Voltage	-35	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. **NOTES:**

Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charac	Off Characteristics					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_G = 1.0 \mu A$	-35			V
I _{GSS}	Gate Reverse Current	V _{GS} = -20V, V _{DS} = 0			-100	pA
V _{GS} (off)	Gate Source Cut-off Voltage	V _{DS} = 15V, I _D = 1.0nA	-2.5		-6.0	V
V _{GS}	Gate Source Voltage	$V_{DS} = 15V, I_D = 500\mu A$	-1		-5.5	V
On Charac	On Characteristics					
I _{DSS}	Zero-Gate Voltage Drain Current	V _{GS} = 15V, V _{GS} = 0	5		15	mA
V _{GS} (f)	Gate-Source Forward Voltage	V _{DS} = 0, I _G = 1.0mA			1	V
Small Sign	Small Signal Characteristics					
g _{fs}	Forward Transfer Conductance *	$V_{DS} = 15V, V_{GS} = 0, f = 1.0kHz$	4500		7500	μmhos
g _{os}	Output Conductance *	$V_{DS} = 15V, V_{GS} = 0, f = 1.0kHz$			50	μmhos
C _{iss}	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1.0MHz$			4.0	pF
Crss	Reverse Transfer Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1.0MHz$			0.8	pF
C _{oss}	Output Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1.0MHz$			2.0	pF
NF	Noise Figure	V_{DS} = 15V, V_{GS} = 0, I_{D} = 5mA, R_{g} = 1k Ω , f = 400MHz			4.0	dB

^{*} Pulse Test: Pulse Width \leq 300ms, Duty Cycle \leq 2%

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

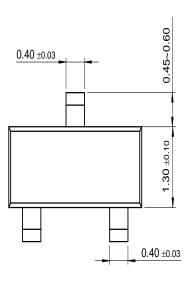
²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

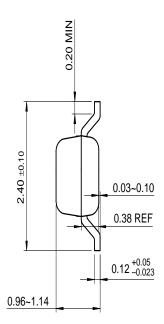
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	225 1.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W

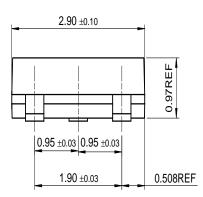
^{*} Device mounted on FR-4 PCB 1.6" \times 1.6" \times 0.06".

Mechanical Dimensions

SOT-23







Dimensions in Millimeters

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